
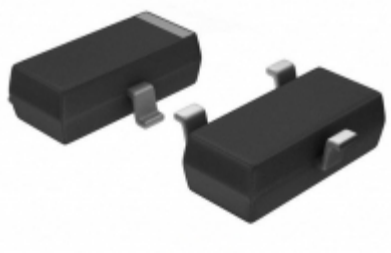






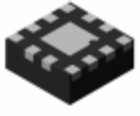




|   |  |                                     |
|---|--|-------------------------------------|
|   | <h2 style="color: red;">DMN13H750S-7</h2>  |                                     |
|   | <b>Hersteller-Teilenummer:</b>   | <a href="#">DMN13H750S-7</a>        |
|  | <b>Hersteller / Marke:</b>   | <a href="#">Diodes Incorporated</a> |
|   | <b>Teil der Beschreibung:</b>  | MOSFET N-CH 130V 1A SOT23           |
| <b>Datenblätter:</b>  |  <a href="#">DMN13H750S-7.pdf</a> |                                     |
| <b>RoHs Status:</b>   | Bleifrei / RoHS-konform  |                                     |
| <b>Lagerzustand:</b>  | New original, 30626 pcs Stock Available.   |                                     |
| <b>Liefern von:</b>   | Hong Kong  |                                     |
| <b>Versandweg:</b>  | DHL/Fedex/TNT/UPS/EMS  |                                     |
| <p>Image may be representation.<br/>See specs for product details.</p>            |  |                                     |

### Spezifikationen

|  |   |
|--|---|
| Teilenummer                                      | <a href="#">DMN13H750S-7</a>  |
| Hersteller                                       | <a href="#">Diodes Incorporated</a>                                 |
| Beschreibung                                     | MOSFET N-CH 130V 1A SOT23   |
| Kategorie  | <a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a> |
| Teilstatus                                       | 30626 pcs Stock   |
| Serie  | -   |
| Technologie                                      | MOSFET (Metal Oxide)  |
| Betriebstemperatur                               | -55°C ~ 150°C (TJ)  |
| Befestigungsart                                  | Surface Mount   |
| Verpackung / Gehäuse                             | TO-236-3, SC-59, SOT-23-3   |
| Supplier Device-Gehäuse                          | SOT-23  |
| Verlustleistung (max)                            | 770mW (Ta)  |
| Typ FET  | N-Channel   |
| FET-Merkmal                                      | -   |
| Drain-Source-Spannung (Vdss)                     | 130V  |
| Strom - Ununterbrochener Abfluss (Id) bei 25 ° C | 1A (Ta)   |
| Rds On (Max) @ Id, Vgs                           | 750 mOhm @ 2A, 10V  |
| VGS (th) (Max) @ Id                              | 4V @ 250µA  |
| Gate Charge (Qg) (Max) @ Vgs                     | 5.6nC @ 10V   |
| Eingabekapazität (Ciss) (Max) @ Vds              | 231pF @ 25V   |
| Antriebsspannung (Max Rds On, Min Rds On)        | 6V, 10V   |
| Vgs (Max)  | ±20V  |
| Verpackung                                       | Original-Reel®  |



















































DMN13H750S-7 ist neu im Original, Suche DMN13H750S-7 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie DMN13H750S-7 Diodes Incorporated mit Garantie und Vertrauen. Anfrage DMN13H750S-7: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

|  |  |   |   |
|--|--|---|---|
|  <p><b>DMN2004DMK</b><br/>DIODES<br/>DMN2004DMK DIODES</p>                                    |  <p><b>DMN16M9UCA6-7</b><br/>Diodes Incorporated<br/>MOSFET 2 N-CHANNEL X3-<br/>DSN2718-6</p> |  <p><b>DMN1150UFL3-7</b><br/>Diodes Incorporated<br/>MOSFET 2N-CHA 12V 2A<br/>DFN1310</p> |  <p><b>DMN1250UFEL-7</b><br/>Diodes Incorporated<br/>MOSFET BVDSS: 8V 24V U-<br/>QFN1515-1</p> |
|  <p><b>DMN13M9UCA6-7</b><br/>Diodes Incorporated<br/>MOSFET 2 N-CHANNEL X3-<br/>DSN3518-6</p> |  <p><b>DMN13H1750S-7</b><br/>DIODES<br/>DMN13H1750S-7 DIODES</p>                              |  <p><b>DMN15H310SK3-13</b><br/>Diodes Incorporated<br/>MOSFET NCH 150V 8.3A TO252</p>     |  <p><b>DMN1260UFA-7B</b><br/>Diodes Incorporated<br/>MOSFET N-CH 12V 0.5A<br/>X2DFN-3</p>      |

### heiße Teile

Mehr

- |   |   |  |   |   |
|---|---|--|---|---|
|  DMN10H099SK3    |  DMN10H099SK3-13 |  DMN10H100SK3       |  DMN10H120SE    |  DMN10H120SE-13  |
|  DMN10H120SFG    |  DMN10H120SFG-7  |  DMN10H120SFG-7     |  DMN10H170SFDE  |  DMN10H170SFDE-7 |
|  DMN10H170SFDE-7 |  DMN10H170SK3    |  DMN10H170SK3-13-79 |  DMN10H170SVT-7 |  DMN10H170SVTQ-7 |
|  DMN10H220L-7    |  DMN10H220LE     |  DMN10H220LE-13     |  DMN10H220LQ    |  DMN10H220LQ-7   |
|  DMN10H220LVT-7  |  DMN10H700S      |  DMN10H700S-7       |  DMN1150UFB-7B  |  DMN13H1750S-7   |
|  DMN15H310SE-13  |  DMN2004DMK      |  DMN2004DMK-7       |  DMN2004DWK-7   |  DMN2004DWK-7-F  |
|  DMN2004K-7      |  DMN2004K-7-F    |  DMN2004TK-7        |  DMN2004TK-7-F  |  DMN2004VK       |
|  DMN2004VK-7     |  DMN2004VK-7-G   |  DMN2004WK-7        |  DMN2004WKQ-7   |  DMN2005DLP4K-7  |
|  DMN2005K-7      |  DMN2005K-7-F    |  DMN2005LP4K-7      |  DMN2005LPK-7   |  DMN2009LSS      |
|  DMN2009LSS-13   |  DMN2009LSS-13-F |  DMN2011UFX-7       |  DMN2013UFDE-7  |  DMN2013UFDEQ-7  |

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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